

IN THE SPECIFICATION

Please replace paragraph [0001] with the following amended paragraph:

[0001] This application is a continuation-in-part of application Ser. No. 10/282,276 filed Oct. 28, 2002, now U.S. Pat. No. 6,689,486, which was a continuation of application Ser. No. 09/795,555 (now abandoned) filed Feb. 28, 2001, which claims the benefit of U.S. Provisional Application No. 60/185,841 filed Feb. 29, 2000 in the names of Ken K. Ho, Gregory P. Carman and Peter A. Jardine, entitled "Bimorphic Compositionally-Graded, Sputter-Deposited, Thin Film Shape Memory Device," the disclosures of each of the foregoing applications being incorporated in its entirety herein.